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**ON Semiconductor®** 

# FSA642 Low-Power, Three-Port, High-Speed MIPI Switch

### Features

- Low On Capacitance: 7.0 pF Typical
- Low On Resistance: 7.0 Ω Typical
- Wide -3db Bandw idth: 1 GHz Typical
- 24-Lead UMLP (2.5 x 3.4 mm) Package
- 8 kV ESD Rating; >16 kV Pow er/GND ESD Rating

### **Applications**

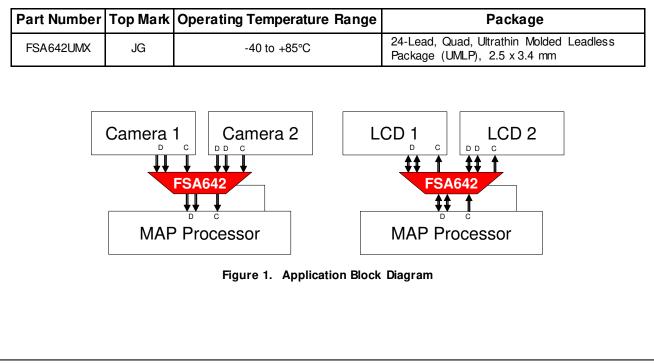
- Dual Camera Applications for Cell Phones
- Dual LCD Applications for Cell Phones, Digital Camera Displays, and View finders

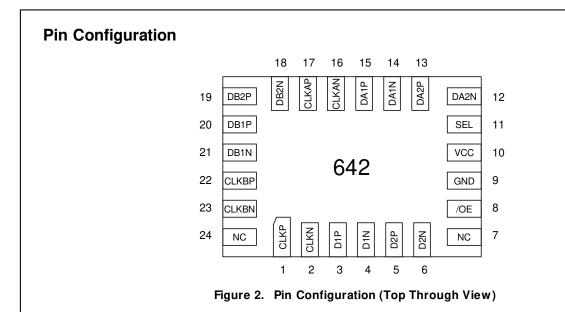
### Description

The FSA642 is a bi-directional, low -pow er, high-speed analog switch. The pin out is designed to ease differential signal layout and is configured as a triplepole, double-throw switch (TPDT). The FSA642 is optimized for switching between two MIPI devices, such as cameras or LCD displays and on-board Multimedia Application Processors (MAP).

The FSA642 is compatible with the requirements of Mobile Industry Processor Interface (MIPI). The low - capacitance design allows the FSA642 to switch signals that exceed 500 MHz in frequency. Superior channel-to-channel crosstalk immunity minimizes interference and allows the transmission of high-speed differential signals and single-ended signals, as described by the MIPI specification.

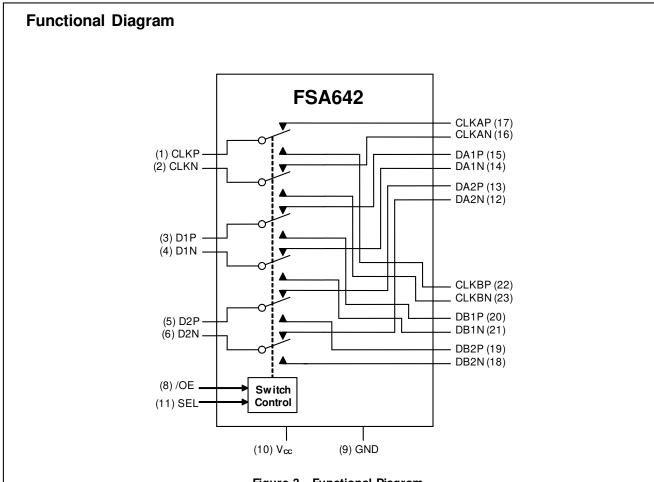
### **Ordering Information**





# **Pin Definitions**

Pin #	Name	Description
1, 2	CLKP, CLKN	Clock Path (Common)
3, 4	D1P, D1N	Data Path 1 (Common)
5, 6	D2P, D2N	Data Path 2 (Common)
7, 24	NC	No Connect (Float)
8	/OE	Output Enable (Active Low)
9	GND	Ground
10	VCC	Pow er
11	SEL	Select (0=A, 1=B)
12, 13	DA2N, DA2P	Data Path (A2)
14, 15	DA1N, DA1P	Data Path (A1)
16, 17	CLKAN, CLKAP	Clock Path (A)
18, 19	DB2N, DB2P	Data Path (2B)
20, 21	DB1P, DB1N	Data Path (1B)
22, 23	CLKBP, CLKBN,	Clock Path (B)





## **Truth Table**

SEL	/OE	Function
Don't Care	HIGH	Disconnect
LOW	LOW	D1, D2, CLK=DA1, DA2, CLKA
HIGH	LOW	D1, D2, CLK=DB1, DB2, CLKB

### **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Min.	Max.	Unit	
Vcc	Supply Voltage		-0.50	+5.25	V
VCNTRL	DC Input Voltage (SEL, /OE) <sup>(1)</sup>		-0.5	Vcc	V
Vsw	DC Switch I/O Voltage <sup>(1)</sup>		-0.5	V <sub>CC</sub> + 0.3	V
lк	DC Input Diode Current		-50		mA
Юит	DC Output Current			50	mA
T <sub>STG</sub>	Storage Temperature		-65	+150	°C
		All Pins		6.5	
ESD	Human Body Model, JEDEC: JESD22-A114	VO to GND		8.0	kV
200		Pow er to GND		16.0	
	Charged Device Model, JEDEC: JESD22-C10	1		2.5	

Note:

1. The input and output negative ratings may be exceeded if the input and output diode current ratings are observed.

### **Recommended Operating Conditions**

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. ON Semiconductor does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit
Vcc	Supply Voltage	2.65	4.30	V
V <sub>CNTRL</sub>	Control Input Voltage (SEL, /OE) <sup>(2)</sup>	0	V <sub>CC</sub>	V
V <sub>SW</sub>	Switch I/O Voltage	-0.5	V <sub>CC</sub> -1	V
T <sub>A</sub>	Operating Temperature	-40	+85	°C

Note:

2. The control input must be held HIGH or LOW; it must not float.

## **DC Electrical Characteristics**

All typical values are  $T_A=25^{\circ}C$  unless otherwise specified.

Symbol	nbol Parameter Conditions V <sub>cc</sub> (V)	Conditions	V (V)	T <sub>A</sub> =-40 to +85 <sup>o</sup> C			Units
Symbol		Min.	Тур.	Max.	Units		
Vık	Clamp Diode Voltage	l <sub>IN</sub> =-18 mA	2.775			-1.2	V
lın	Control Input Leakage	V <sub>SW</sub> =0 to 4.3 V	4.3	-1		1	μA
Vін	Input Valtaga Ligh	V <sub>IN</sub> =0 to V <sub>CC</sub>	2.650 to 2.775	1.3			v
VIH	Input Voltage High	VIN=0 to VCC	4.3	1.7			v
VIL	Input Voltage Low	V <sub>IN</sub> =0 to V <sub>CC</sub>	2.650 to 2.775			0.5	V
loz	Off-State Leakage	A,B=0+0.3 V to V <sub>CC</sub> -0.3	4.3	-2		2	μA
lcc	Quiescent Supply Current	V <sub>CNTRL</sub> =0 or V <sub>CC</sub> , l <sub>OUT</sub> =0	4.3			1.0	μA
Сст	Increase in I <sub>CC</sub> Current Per Control Voltage and V <sub>CC</sub>	V <sub>CNTRL</sub> =1.8 V	2.775			1.5	μΑ

### **DC Electrical Characteristics, Low-Speed Mode**

All typical values are T<sub>A</sub>=25°C unless otherwise specified.

Symbol	Parameter	Conditions	V <sub>cc</sub> (V)	T <sub>A</sub> =-40 to +85⁰C			Units
Cymbol	i didiliciti	Conditions	• cc (•)	Min.	Тур.	Max.	onito
Ron	LS Switch On Resistance <sup>(3)</sup>	$V_{SW}$ =1.2 V, $I_{ON}$ =-10 mA, Figure 4	2.65		10	14	Ω
$\Delta R_{ON}$	LS Delta R <sub>ON</sub> <sup>(4)</sup>	$V_{SW}$ =1.2 V, $I_{ON}$ =-10 mA (Intra-pair)	2.65		0.65		Ω

Notes:

3. Measured by the voltage drop between A/B and CLK/Dn pins at the indicated current through the switch.

4. Guaranteed by characterization.

### **DC Electrical Characteristics, High-Speed Mode**

All typical values are  $T_A\!\!=\!\!25^\circ\!C$  unless otherwise specified.

Symbol	Parameter	Conditions	V <sub>cc</sub> (V)	T <sub>A</sub> =-40 to +85⁰C			Units
O y i i boi	rarameter	Conditions	• cc (•)	Min.	Тур.	Max.	
R <sub>ON</sub>	HS Switch On Resistance <sup>(5)</sup>	$V_{SW}\!\!=\!\!0.4$ V, $I_{ON}\!\!=\!\!-10$ mA, Figure 4	2.65		7.0	9.5	Ω
$\Delta R_{ON}$	HS Delta R <sub>ON</sub> <sup>(6)</sup>	$V_{SW}=0.4 V$ , $I_{ON}=-10 mA$ (Intra-pair)	2.65		0.65		Ω

Notes:

5. Measured by the voltage drop between A, B, and Dn pins at the indicated current through the switch.

6. Guaranteed by characterization.

All values are at  $R_L$ =50 $\Omega$  and  $R_S$ =50 $\Omega$  and all typical values are  $V_{CC}$ =2.775V at  $T_A$ =25°C unless otherwise specified.

Symbol	ymbol Parameter Conditions V <sub>cc</sub> (V)	Conditions		T <sub>A</sub> =-40°C to +85°C			Units
Symbol		V <sub>CC</sub> (V)	Min.	Тур.	Max.	Units	
OIRR	Off Isolation <sup>(7)</sup>	f=100 MHz, $R_T$ =50 $\Omega$ Figure 14	2.775		-35		dB
Xtalk	Non-Adjacent Channel Crosstalk <sup>(7)</sup>	f=100 MHz, RT=50 $\Omega$ Figure 15	2.775		-55		dB
BW	-3 db Bandwidth <sup>(7)</sup>	CL=0 pF, Rτ=50 Ω Figure 13	2.775		1.0		GHz
ton	Turn-On Time SEL, /OE to Output	C <sub>L</sub> =5 pF, V <sub>SW</sub> =1.2 V Figure 6, Figure 7	2.650 to 2.775		20	37	ns
toff	Turn-Off Time SEL, /OE to Output	C <sub>L</sub> =5 pF, V <sub>SW</sub> =1.2 V Figure 6, Figure 7	2.650 to 2.775		15	27	ns
tPD	Propagation Delay <sup>(7)</sup>	C∟=5 pF Figure 6, Figure 8	2.775		0.25		ns
t <sub>BBM</sub>	Break-Before-Make Time	C∟=5 pF, Vsw1=Vsw2=1.2 V Figure 12	2.650 to 2.775	3	5	8	ns

Note:

7. Guaranteed by characterization.

### AC Electrical Characteristics, High-Speed

All typical values are  $V_{CC}$ =2.775V at T<sub>A</sub>=25°C unless otherwise specified.

Symbol	Parameter	Conditions	T <sub>A</sub> =-40⁰C to +85⁰C			Units
Symbol	Falameter	Conditions	Min.	Тур.	Max.	onns
tsk(Part_Part)	Channel-to-Channel Skew Across Multiple Parts <sup>(8,9)</sup>	$V_{SW}=0.2 \text{ Vdiff}_{PP}, C_L=5 \text{ pF}$		40	80	ps
tsk(Chl_Chl)	Channel-to-Channel Skew Within a Single Part <sup>(8)</sup>	$V_{SW}$ =0.2 Vdiff <sub>PP</sub> , CL=5 pF, Figure 9		15	30	ps
t <sub>SK(Pulse)</sub>	Skew of Opposite Transitions in the Same Differential Channel <sup>(8)</sup>	$V_{SW}=0.2 \text{ Vdiff}_{PP}, C_L=5 \text{ pF}$		10	20	ps

Notes:

8. Guaranteed by characterization.

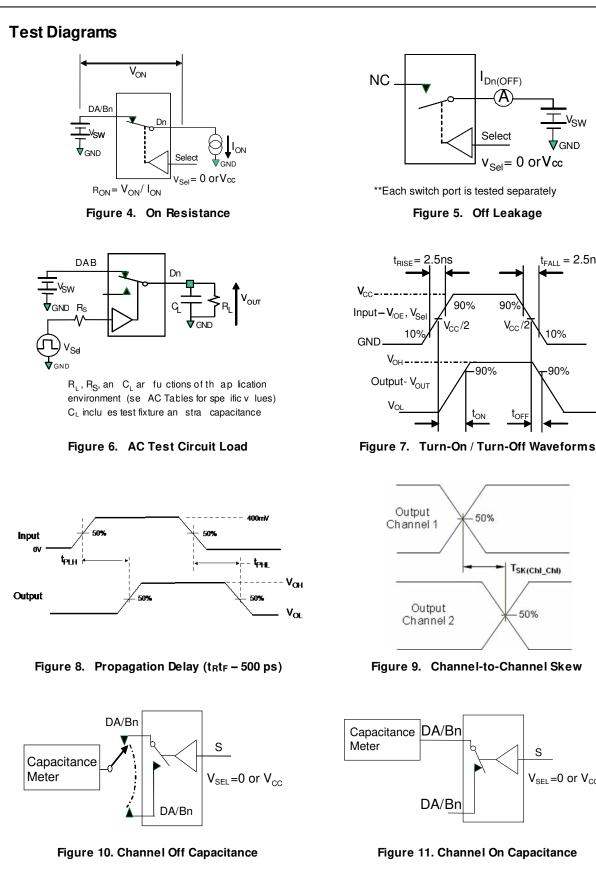
9. Assumes the same  $V_{CC}$  and temperature for all devices.

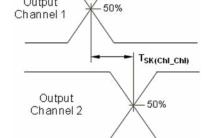
### Capacitance

Symbol	Parameter	Conditions	T <sub>A</sub> =-40°C to +85°C			Units
Symbol		Conditions	Min.	Тур.	Max.	Units
Cin	Control Pin Input Capacitance <sup>(10)</sup>	V <sub>CC</sub> =0 V		1.5		
CON	Dn/CLK- On Capacitance <sup>(10)</sup>	V <sub>CC</sub> =2.775 V, /OE=0 V, f=1 MHz, at 25°C, Figure 11	6.0	7.0	9.0	pF
COFF	Dn/CLK Off Capacitance <sup>(10)</sup>	V <sub>CC</sub> =2.775 V, /OE=2.775 V, f=1 MHz, Figure 10		2.5		

Note:

10. Guaranteed by characterization.





I<sub>Dn(OFF)</sub>

A

Select

90%

-90%

[<sub>ON</sub>

*I*<sub>CC</sub>/2

90%

V<sub>CC</sub>

I OF

 $v_{Sel} = 0 \text{ or } V_{CC}$ 

GND

 $t_{FALL} = 2.5 ns$ 

10%

-90%

Figure 9. Channel-to-Channel Skew

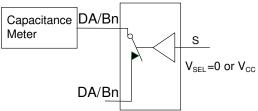
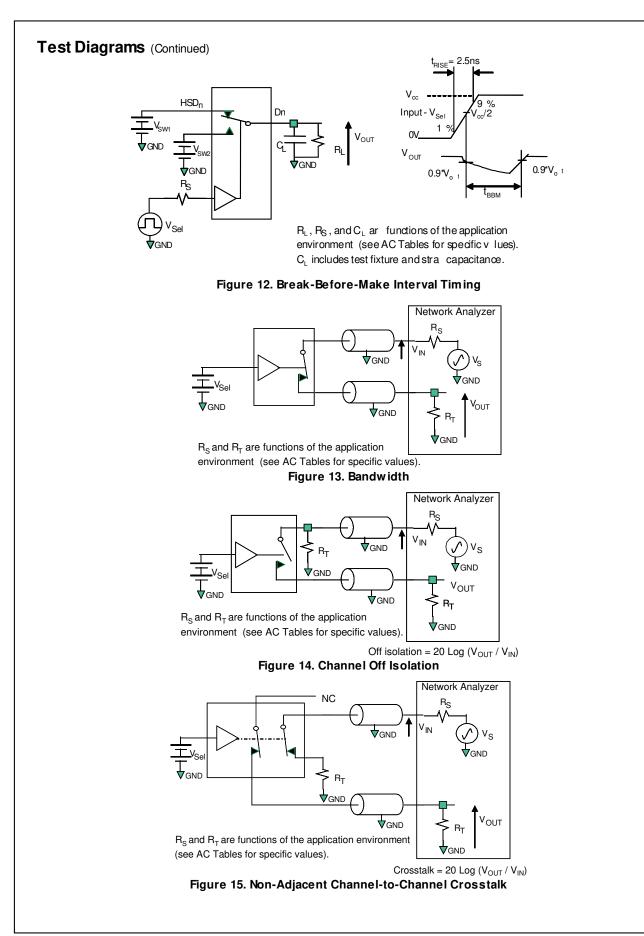
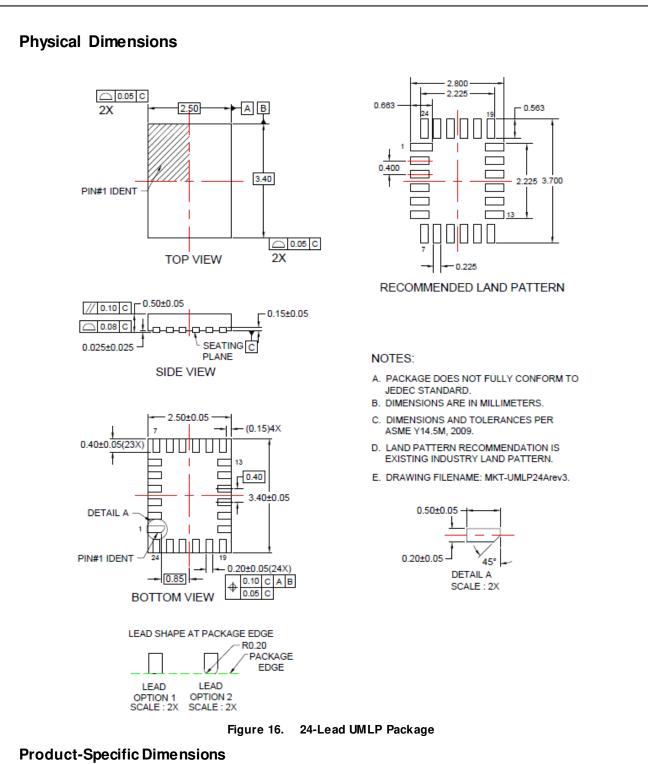


Figure 11. Channel On Capacitance





Description	Nominal Values (mm)	Description	Nominal Values (mm)
Overall Height	0.500	Lead Length (23x)	0.4
PKG Standoff	0.026	Lead Length, Pin 1 (1x)	0.5
Lead Thickness	0.152	Lead Pitch	0.4
Lead Width (24x)	0.200	Body Length (X)	3.4
	·	Body Width (Y)	2.5

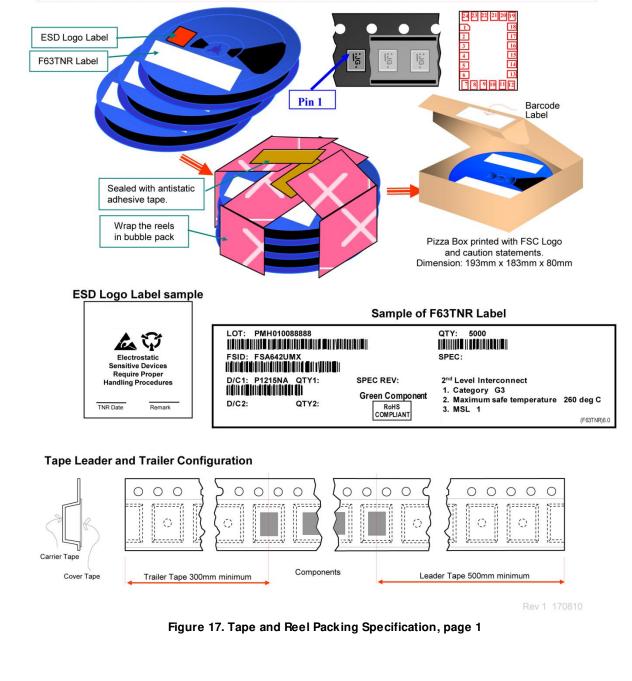
# 2.5x3.4 UMLP24L Packing - Embossed Tape FSA642UMX

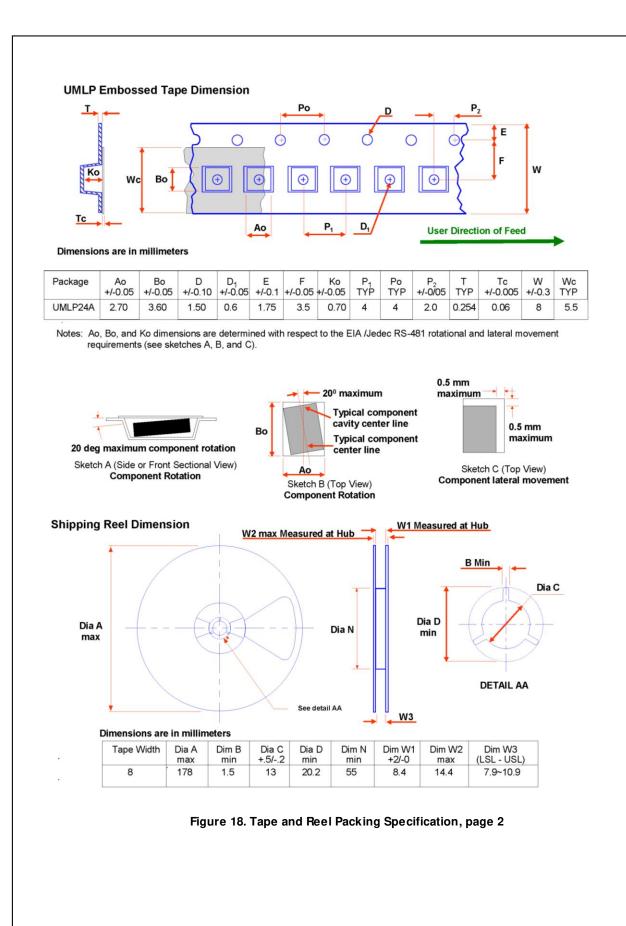
### Packing Description:

UMLP 24 pins products are classified under Moisture Sensitive Level 1.

The carrier tape is made from dissipative polystyrene or polycarbonate resin. The cover tape is a multilayer film primarily composed of polyester film, adhesive layer, heat activated sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 5000 units per 178 mm diameter reel. Up to three reels are packed in each intermediate box. The reels is made of polystyrene plastic (anti-static coated or intrinsic).

These full reels are individually barcode labeled and placed inside a pizza box made of recyclable corrugated brown paper with a Fairchild logo printing. The reel is packed single reel in the pizza box. And these pizza boxes are placed inside a barcode labeled shipping box which comes in different sizes depending on the number of parts shipped.





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